

Transparent conducting oxide NiCo₂O₄

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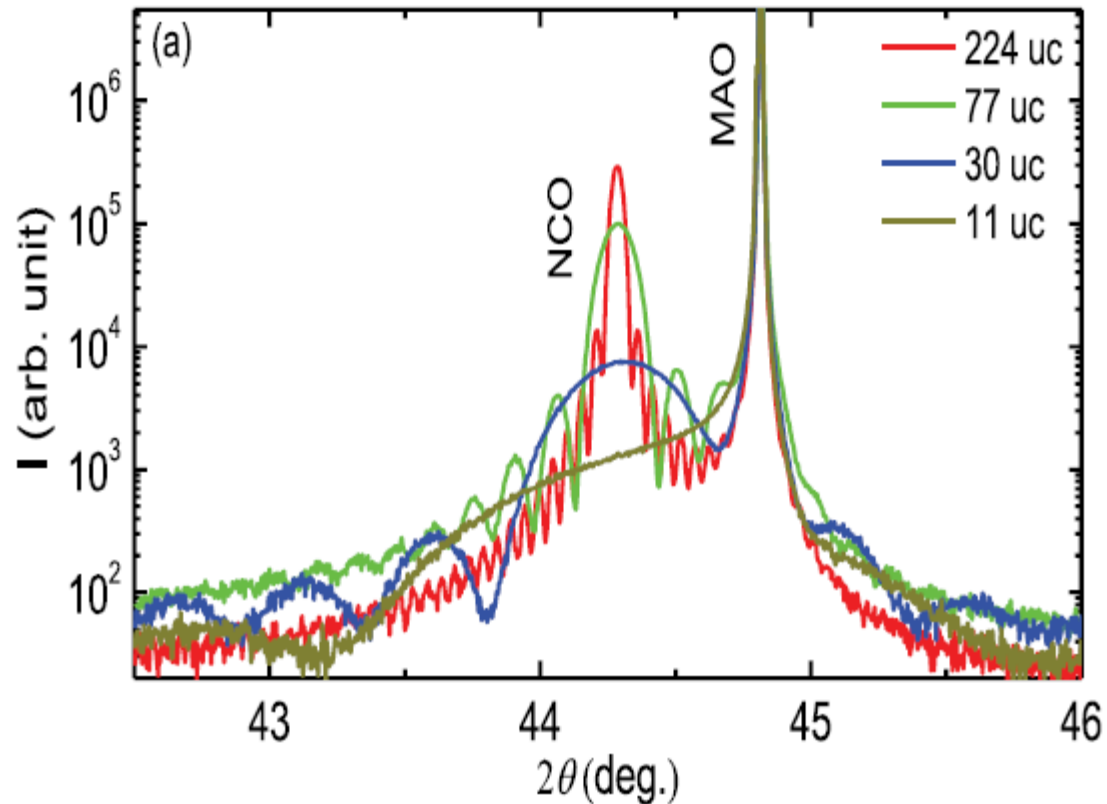
Introduction

- The structural examination of the films reveals that the epitaxial strain is independent of the films' thickness.
- the films are metallic with p-type conduction and ferromagnetic down to 2 unit cells with an enhanced coercive field in the films thinner than 30 unit cells.
- the observed resistivity minimum results from the disorder-induced quantum interference effects.

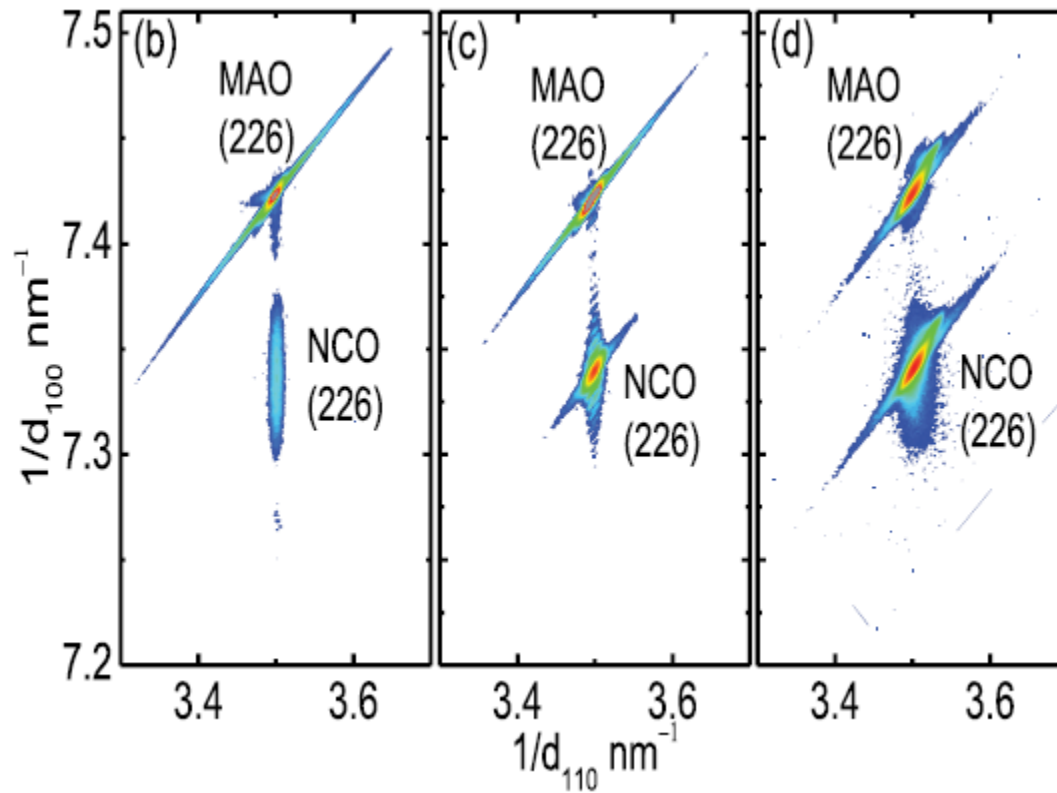
Experiment details

- Substrate :MgAl₂O₄
- T= 350 C
- P=50 milli Torr O₂ pressure
- thickness ranging from 1 uc to 228 uc
- Measured by X-ray diffraction(HR-XRD), x-ray reflectivity (XRR), superconducting quantum interference device (SQUID) magnetometer

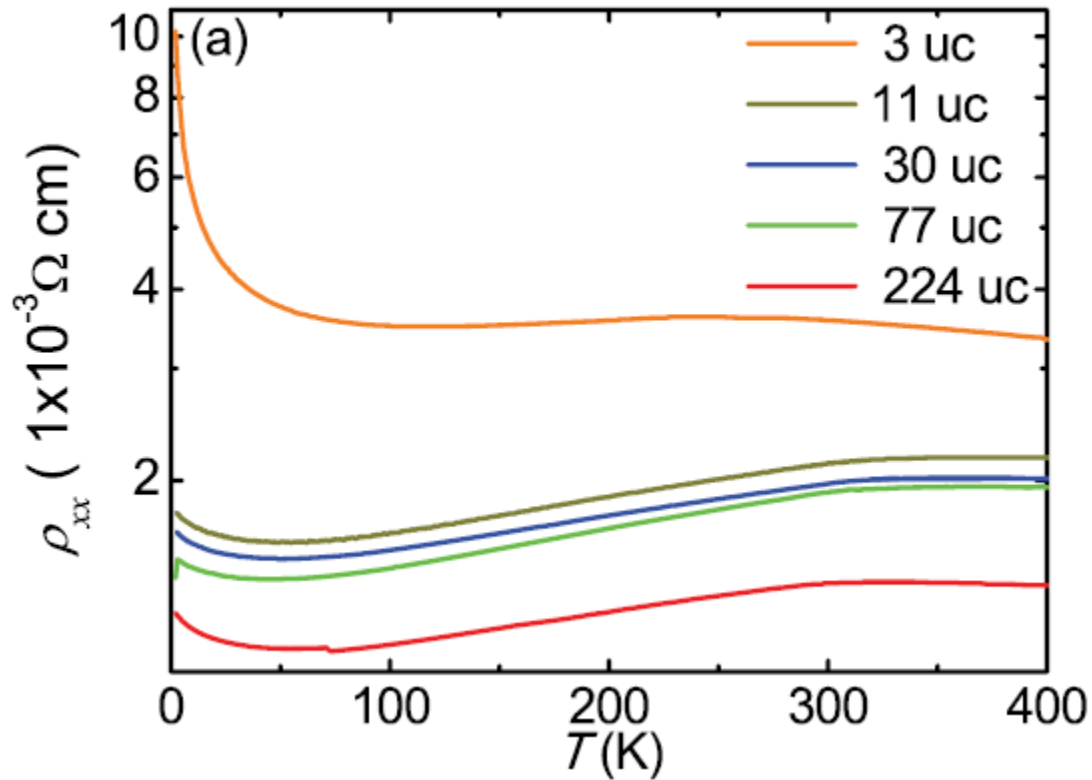
Results



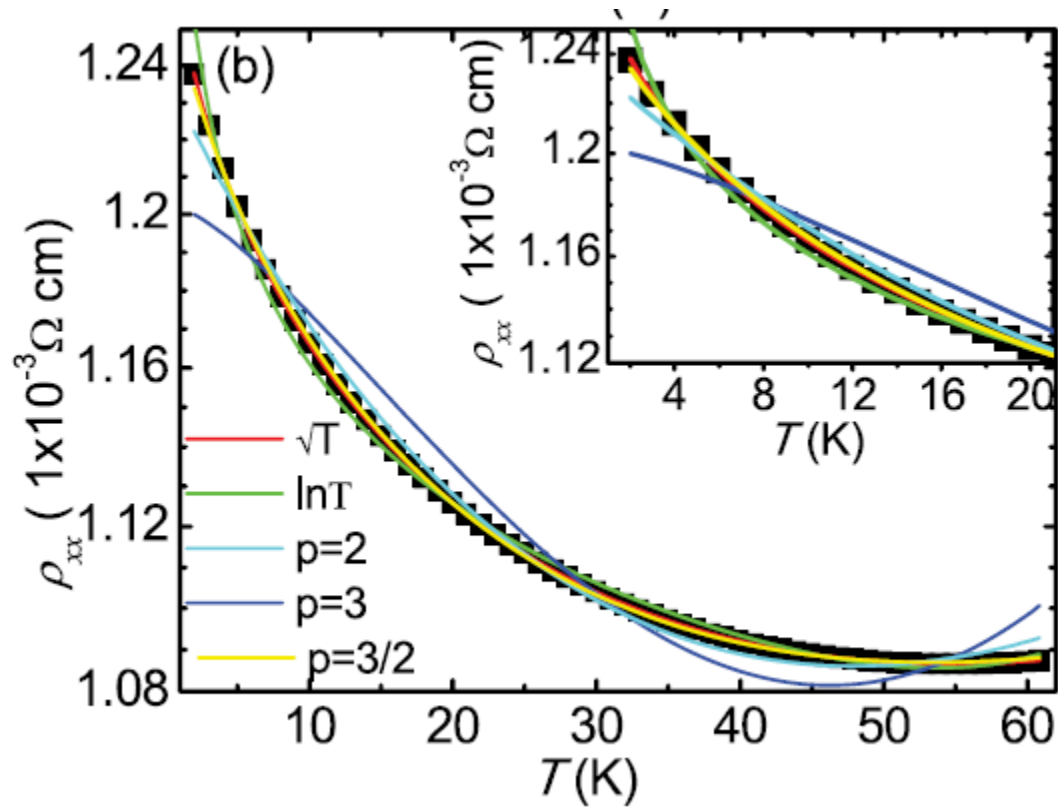
XRD 2θ - θ scans through the (004) symmetric reflections of the film and substrate for the 11, 30, 77, and 224 uc thick films



HR-XRD reciprocal space maps around the (226) reflections of the NiCo₂O₄ films on MgAl₂O₄ substrate with the thickness 11, 224, and 875 unit cells



In-plane resistivity ρ vs. temperature T for the NiCo_2O_4 with the thicknesses of 3, 11, 30, 77, and 224 unit cells



Resistivity $\rho(T)$ for the 224 uc film and the fitted curves.

we fit the temperature dependence of $\rho(T)$ in the 2–60K range with the functional form

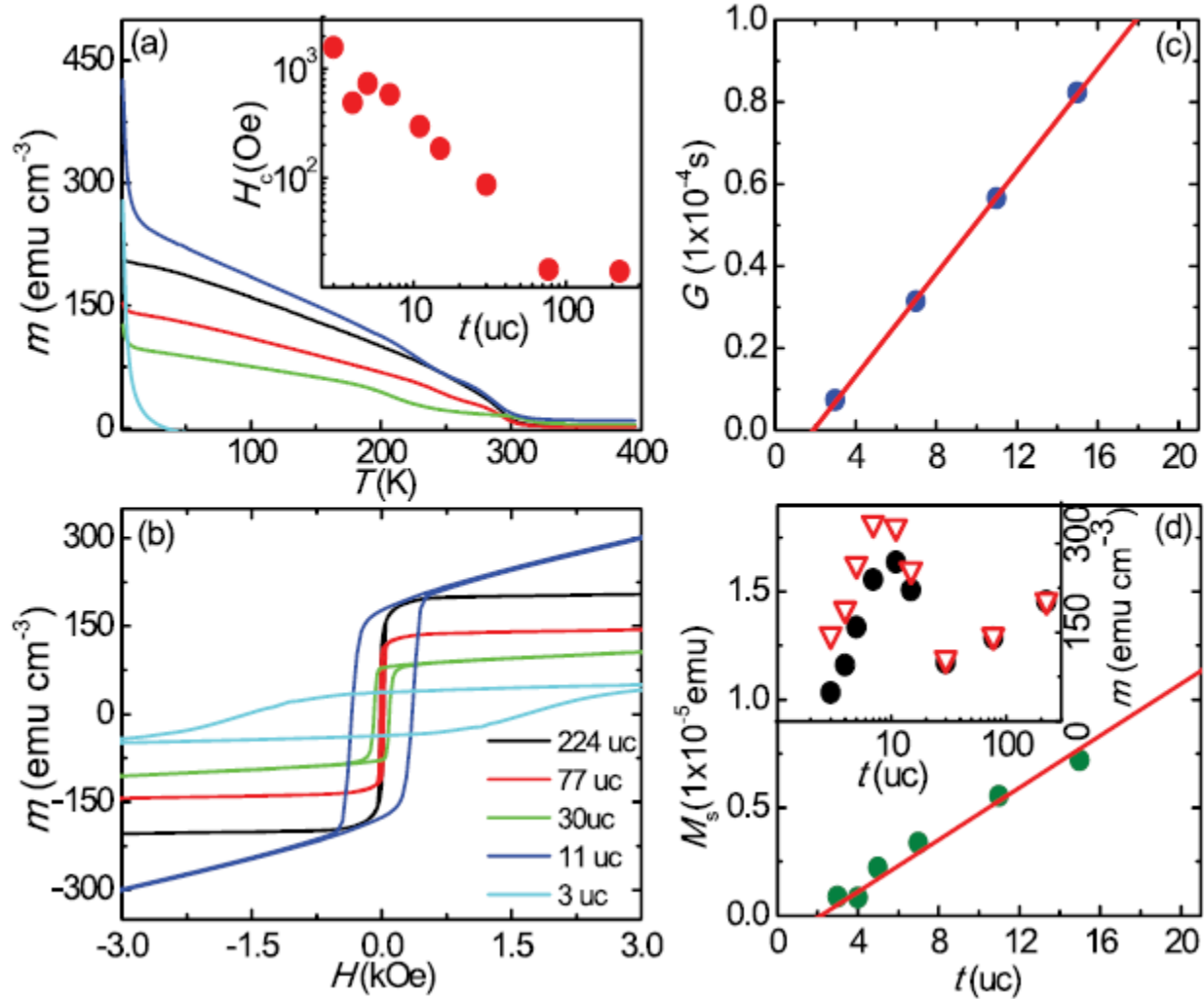
$$\rho(T) = \frac{1}{\sigma_0 + C \ln T} + AT^n$$

The disorder-induced localization tendencies in the 3D limit are described by the following equations

$$\rho(T) = \frac{1}{\sigma_0 + B\sqrt{T}} + AT^n$$

$$\rho(T) = \frac{1}{\sigma_0 + BT^{p/2}} + AT^n$$

magnetic measurements



Summary

- The structural analysis revealed that the epitaxial strain in the NiCo₂O₄/MgAl₂O₄ (001) films is independent of the films' thickness up to 700 nm.
- the films remain metallic and magnetic down to 2 μ c in thickness.
- The resistivity minimum with T_{min} 50–60K is explained as the consequence of the disorder-induced quantum interference effects.
- The enhanced magnetic properties and the metallicity make the ultrathin epitaxial NiCo₂O₄ films a good candidate material for spintronics

Thanks